

# Entropic Effect on the Rate of Dislocation Nucleation

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## Abstract

Dislocation nucleation is essential to our understanding of plastic deformation, ductility and mechanical strength of crystalline materials. Molecular dynamics simulation has played an important role in uncovering the fundamental mechanisms of dislocation nucleation, but its limited time scale remains a significant challenge for studying nucleation at experimentally relevant conditions. Here we show that dislocation nucleation rates can be accurately predicted over a wide range of conditions by determining the activation free energy from umbrella sampling. Our data reveal very large activation entropies, which contribute a multiplicative factor of many orders of magnitude to the nucleation rate. The activation entropy at constant strain is caused by thermal expansion, with negligible contribution from the vibrational entropy. The activation entropy at constant stress is significant larger than that at constant strain, as a result of thermal softening. The large activation entropies are caused by anharmonic effects, showing the limitations of the harmonic approximation widely used for rate estimation in solids. Similar behaviors are expected to occur in other nucleation processes in solids.

Nucleation plays an important role in a wide range of physical, chemical and biological processes<sup>1-6</sup>. In the last two decades, the nucleation of dislocations in crystalline solids has attracted significant attention, not only for the reliability of microelectronic devices<sup>7</sup>, but also as a responsible mechanism for incipient plasticity in nano-materials<sup>8-10</sup> and nano-indentation<sup>11-13</sup>. However, predicting the nucleation rate as a function of temperature and stress from fundamental physics is extremely difficult. Because the critical nucleus can be as small as a few lattice spacings, the applicability of continuum theory<sup>14</sup> becomes questionable. At the same time, the time scale of molecular dynamics (MD) simulations is about ten orders of magnitude smaller than the experimental time scale. Hence MD simulations of dislocation nucleation are limited to conditions at which the nucleation rate is extremely high<sup>15,16</sup>.

One way to predict dislocation nucleation rate under common experimental loading rates<sup>17</sup> is to combine the transition state theory (TST)<sup>5,18</sup> and the nudged-elastic-band (NEB) method<sup>19</sup>. TST predicts that the nucleation rate per nucleation site in a crystal subjected to constant strain  $\gamma$  can be written as

$$I^{\text{TST}} = \nu_0 \exp \left[ -\frac{F_c(T, \gamma)}{k_B T} \right] \quad (1)$$

where  $F_c$  is the activation free energy,  $T$  is temperature, and  $k_B$  is Boltzmann's constant. The frequency prefactor is  $\nu_0 = k_B T/h$ , where  $h$  is Planck's constant. Note that  $F_c(T, \gamma) = E_c(\gamma) - T S_c(\gamma)$ , where  $E_c$  and  $S_c$  are the activation energy and activation entropy, respectively. Here we assume the dependence of  $E_c$  and  $S_c$  on  $T$  is weak, which is later confirmed numerically for  $T \leq 400\text{K}$ . For a crystal subjected to constant stress  $\sigma$ ,  $F_c(T, \gamma)$  in Eq. (1) should be replaced by the activation Gibbs free energy  $G_c(T, \sigma) = H_c(\sigma) - T S_c(\sigma)$ , where  $H_c$  is the activation enthalpy. Because the NEB method only computes the activation energy, the contribution of  $S_c$  is often ignored in rate estimates in solids. Recently, an approximation of  $S_c(\sigma) = H_c(\sigma)/T_m$  is used<sup>17</sup>, where  $T_m$  is the surface disordering temperature. This approximation was questioned by subsequent MD simulations<sup>20</sup>. The magnitude of  $S_c$  remains unknown because none of the existing methods for computing activation free energies<sup>21-23</sup> has been successfully applied to dislocation nucleation.

We successfully applied the umbrella sampling<sup>21</sup> method to compute the activation free energy for homogeneous and heterogeneous dislocation nucleation in copper. Based on this input, the nucleation rate is predicted using the Becker-Döring theory<sup>24</sup>. Comparison with direct MD simulations at high stress confirms the accuracy of this approach. Both  $F_c(T, \gamma)$

and  $G_c(T, \sigma)$  show significant reduction with increasing  $T$ , corresponding to large activation entropies. For example,  $S_c(\gamma = 0.092) = 9 k_B$  and  $S_c(\sigma = 2 \text{ GPa}) = 48 k_B$  are observed in homogeneous nucleation. We found that  $S_c(\gamma)$  is caused by the anharmonic effect of thermal expansion, with negligible contribution from the vibrational entropy. The large difference in the two activation entropies,  $\Delta S_c \equiv S_c(\sigma) - S_c(\gamma)$ , is caused by thermal softening, which is another anharmonic effect. Similar behaviors are expected to occur in other nucleation processes in solids.

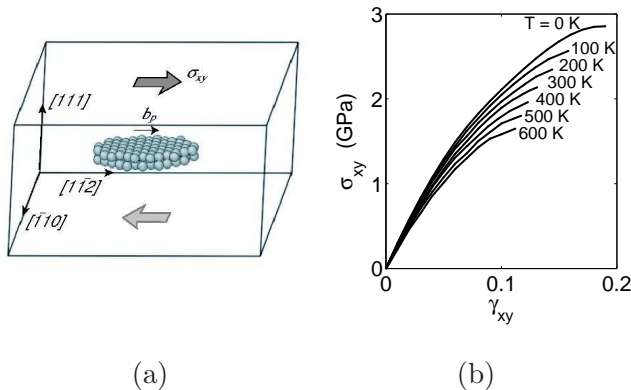


FIG. 1. (a) Schematics of the simulation cell. The spheres represent atoms enclosed by the critical nucleus of a Shockley partial dislocation loop. (b) Shear stress-strain curves of the Cu perfect crystal (before dislocation nucleation) at different temperatures.

For simplicity, we begin with the case of homogeneous dislocation nucleation in the bulk. Even though dislocations often nucleate heterogeneously at surfaces or internal interfaces, homogeneous nucleation is believed to occur in nano-indentation<sup>11</sup> and in a model of brittle-ductile transition<sup>25</sup>. It also provides an upper bound to the ideal strength of the crystal. Our model system is a copper single crystal described by the embedded-atom method (EAM) potential<sup>26</sup>. As shown in Fig. 1(a), the simulation cell is subjected to a pure shear stress along  $[11\bar{2}]$ . The dislocation to be nucleated lies on the  $(111)$  plane and has the Burgers vector of a Shockley partial<sup>27</sup>,  $\mathbf{b}_p = [11\bar{2}]/6$ . Fig. 1(b) shows the shear stress-strain relationship of the perfect crystal at different temperatures (before dislocation nucleation).

In this work, we predict the nucleation rate based on the Becker-Döring (BD) theory,

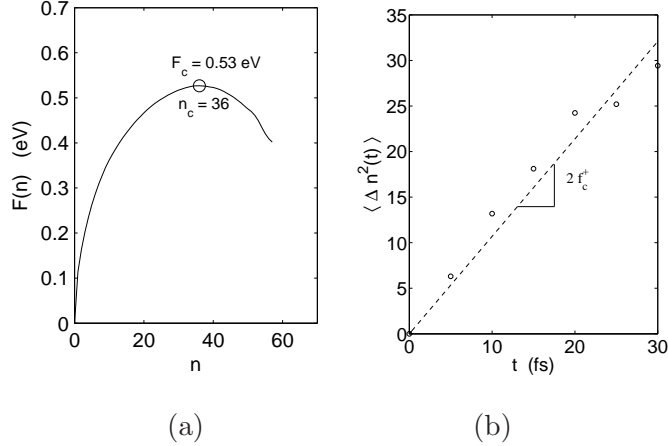


FIG. 2. (a) Free energy of dislocation loop during homogeneous nucleation at  $T = 300$  K,  $\sigma_{xy} = 2.16$  GPa ( $\gamma_{xy} = 0.135$ ) from umbrella sampling. (b) Size fluctuation of critical nuclei from MD simulations.

which expresses the nucleation rate per nucleation site as,

$$I^{\text{BD}} = f_c^+ \Gamma \exp \left[ -\frac{F_c(T, \gamma)}{k_B T} \right] \quad (2)$$

where  $f_c^+$  is the molecular attachment rate, and  $\Gamma$  is the Zeldovich factor (see Methods). The BD theory and TST only differs in the frequency prefactor. Whereas TST neglects multiple recrossing over the saddle point by a single transition trajectory<sup>5</sup>, the recrossing is accounted for in the BD theory through the Zeldovich factor.

First, we establish the validity of the BD theory for dislocation nucleation by comparing it against direct MD simulations at a relatively high stress  $\sigma = 2.16$  GPa ( $\gamma = 0.135$ ) at  $T = 300$ K, which predicts  $I^{\text{MD}} = 2.5 \times 10^8 \text{ s}^{-1}$  (see Methods). The key input to the BD theory is the activation Helmholtz free energy  $F_c(T, \gamma)$ , which is computed by umbrella sampling. The umbrella sampling is performed in Monte Carlo simulations using a bias potential as a function of the order parameter  $n$ , which is chosen as the number of atoms inside the dislocation loop (see Methods).

Fig. 2(a) shows the free energy function  $F(n)$  obtained from umbrella sampling for the specified  $(T, \gamma)$  condition. The maximum of  $F(n)$  gives the activation free energy  $F_c = 0.53 \pm 0.01$  eV and the critical nucleus size  $n_c = 36$ . The Zeldovich factor<sup>30</sup>,  $\Gamma = 0.055$ , is obtained from  $\Gamma \equiv \left( \frac{\eta}{2\pi k_B T} \right)^{1/2}$  where  $\eta = -\partial^2 F(n) / \partial n^2|_{n=n_c}$ .

Using the configurations collected from umbrella sampling with  $n = n_c$  as initial condi-

tions, MD simulations give the attachment rate  $f_c^+ = 5.3 \times 10^{14} \text{ s}^{-1}$  (see Methods). Because the entire crystal is subjected to uniform stress, the number of nucleation sites is the total number of atoms,  $N_{\text{atom}} = 14,976$ . Combining these data, the Becker-Döring theory predicts the total nucleation rate to be  $N_{\text{atom}} I^{\text{BD}} = 6.2 \times 10^8 \text{ s}^{-1}$ , which is within a factor of 3 of the MD prediction. The difference between the two is comparable to our error bar. This agreement is noteworthy because no adjustable parameters (such as the frequency prefactor) is involved in this comparison. It shows that the Becker-Döring theory and our numerical approach are suitable for the calculation of dislocation nucleation rate.

We now examine the dislocation nucleation rate under a wide range of temperature and strain (stress) conditions relevant for experiments and beyond the limited time scale of MD simulations. Fig. 3(a) shows the activation Helmholtz free energy  $F_c(T, \gamma)$  as a function of  $\gamma$  at different  $T$ . The zero temperature data is obtained a minimum-energy-path (MEP) search using a modified version of the string method, similar to that used in<sup>17,31</sup>. The downward shift of  $F_c$  curves with increasing  $T$  is the signature of the activation entropy  $S_c$ . Fig. 3(c) plots  $F_c$  as a function of  $T$  at  $\gamma = 0.092$ . For  $T \leq 400\text{K}$ , the data closely follow a straight line, whose slope gives  $S_c(\gamma) = 9 k_B$ . This activation entropy contributes a significant multiplicative factor,  $\exp(S_c/k_B) \approx 10^4$ , to the absolute nucleation rate, and cannot be ignored.

What causes this rapid drop of activation free energy with temperature? Thermal expansion and vibrational entropy are two candidate mechanisms. To examine the effect of thermal expansion, we performed zero temperature MEP search at  $\gamma = 0.092$ , but with other strain components fixed at the equilibrated values at  $T = 300 \text{ K}$ . This approach is similar to the quasi-harmonic approximation (QHA)<sup>32,33</sup> often used in free energy calculations in solids, except that, unlike QHA, the vibrational entropy is completely excluded here. The resulting activation energy,  $\tilde{E}_c = 2.04 \text{ eV}$ , is indistinguishable from the activation free energy  $F_c = 2.05 \pm 0.01$  at  $T = 300 \text{ K}$  computed from umbrella sampling. Because atoms do not vibrate in the MEP search, this result shows that the dominant mechanism for the large  $S_c(\gamma)$  is thermal expansion, while the contribution from vibrational entropy is negligible. As temperature increases, thermal expansion pushes neighboring atoms further apart and weakens their mutual interaction. This expansion makes crystallographic planes easier to shear and significantly reduces the free energy barrier for dislocation nucleation. In the widely used harmonic approximation of TST, the activation entropy is often attributed to

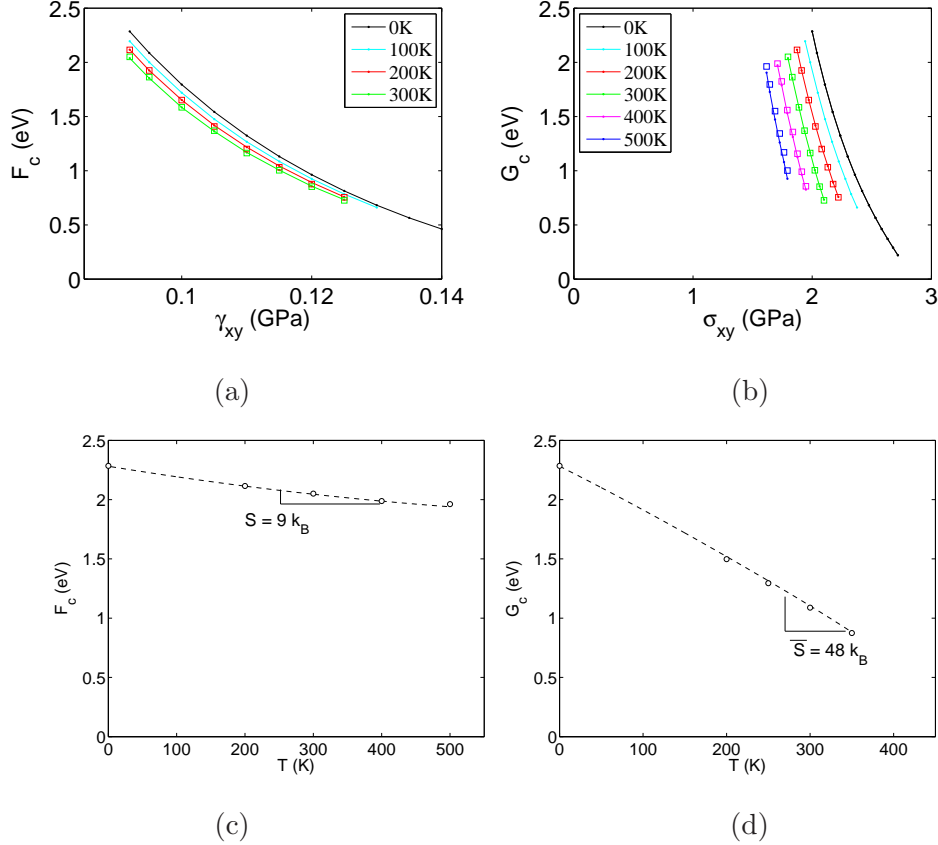


FIG. 3. Activation free energy for homogeneous dislocation nucleation in copper. (a)  $F_c$  as a function of shear strain  $\gamma$  at different  $T$ . The data for  $T = 400\text{K}$  and  $T = 500\text{K}$  are shown in SI appendix. (b)  $G_c$  as a function of shear stress  $\sigma$  at different  $T$ . Squares represent umbrella sampling data and lines represent zero temperature MEP search results using simulation cells equilibrated at different temperatures. (c)  $F_c$  as a function of  $T$  at  $\gamma = 0.092$ . Circles represent umbrella sampling data and dashed line represent a polynomial fit. (d)  $G_c$  as a function of  $T$  at  $\sigma = 2.0$  GPa from polynomial fit.

the vibrational degrees of freedom as  $\nu_0 \exp(S_c/k_B) = (\prod_{i=1}^{\mathcal{N}} \nu_i^m) / (\prod_{i=1}^{\mathcal{N}-1} \nu_i^a)$ , where  $\nu_i^m$  and  $\nu_i^a$  are the positive normal frequencies around the local energy minimum and activated state, respectively<sup>5,18,34</sup>. However, here we see that  $S_c(\gamma)$  arises entirely from the anharmonic effect for dislocation nucleation. At  $T = 400\text{K}$  and  $T = 500\text{K}$ , we observe significant differences between  $F_c$  computed from umbrella sampling and  $\tilde{E}_c$  computed from MEP search in the expanded cell. These difference must also be attributed to anharmonic effects.

While it is easier to control strain  $\gamma$  than stress  $\sigma$  in atomistic simulations, it is usually

easier to apply stress in experiments, and experimental results are often expressed as a function of  $\sigma$  and  $T$ . To bridge between simulations and experiments, it is important to establish a connection between the constant-stress and constant-strain ensembles. In the constant-strain ensemble, the system is described by the Helmholtz free energy  $F(n, T, \gamma)$  where  $n$  is the size of the dislocation loop and the activation Helmholtz free energy is defined as  $F_c(T, \gamma) \equiv F(n_c, T, \gamma) - F(n=0, T, \gamma)$ . In the constant-stress ensemble, the system is described by the Gibbs free energy  $G(n, T, \sigma)$ , from the Legendre transform  $G = F - \sigma \gamma V$ , with  $\sigma \equiv V^{-1} \partial F / \partial \gamma|_{n, T}$ . Similarly,  $G_c(T, \sigma) \equiv G(n_c, T, \sigma) - G(n=0, T, \sigma)$ . We have proved that  $G_c(T, \sigma) = F_c(T, \gamma)$  in the thermodynamic limit of  $V \rightarrow \infty$ , when  $\sigma$  and  $\gamma$  satisfies the stress-strain relation of the perfect crystal,  $\sigma(\gamma, T)$ . The difference between  $F_c$  and  $G_c$  when  $\sigma = \sigma(T, \gamma)$  is of the order  $\mathcal{O}(V^{-1})$ . The details of the proof will be published separately.

Combining the activation Helmholtz free energy  $F_c(T, \gamma)$  shown in Fig. 3(a) and the stress-strain relations shown in Fig. 1(b), we obtain the activation Gibbs free energy  $G_c(T, \sigma)$ , which is shown in Fig. 3(b). We immediately notice that the curves at different temperatures are more widely apart in  $G_c(T, \sigma)$  than that in  $F_c(T, \gamma)$ , indicating a much larger activation entropy in the constant-stress ensemble. For example, Fig. 3(d) plots  $G_c$  as a function of  $T$  at  $\sigma = 2.0$  GPa, from which we can obtain an averaged activation entropy of  $\overline{S}_c(\sigma) = 48 k_B$  in the temperature range of  $[0, 300\text{K}]$ . This activation entropy contributes a multiplicative factor of  $\exp(\overline{S}_c(\sigma)/k_B) \approx 10^{20}$  to the absolute nucleation rate.

The dramatic difference between  $S_c(\gamma)$  and  $S_c(\sigma)$  may seem surprising. Indeed, they are sometimes used interchangeably<sup>35,36</sup>, although the conceptual difference between the two has been pointed out in the context of chemical reactions<sup>37,38</sup>. It is well known that the entropy is independent of the ensemble of choice, i.e.  $S(n, T, \gamma) \equiv \partial F(n, T, \gamma) / \partial T|_{n, \gamma}$  and  $S(n, T, \sigma) \equiv \partial G(n, T, \sigma) / \partial T|_{n, \sigma}$  equal to each other as long as  $\sigma = V^{-1} \partial F / \partial \gamma|_{n, T}$ , which is true by definition. At the same time, the activation entropy is just the entropy difference between the activated state and the metastable state, i.e.  $S_c(T, \gamma) = S(n_c, T, \gamma) - S(n=0, T, \gamma)$  and  $S_c(T, \sigma) = S(n_c, T, \sigma) - S(n=0, T, \sigma)$ . If the entropies in two ensembles can equal each other, it may seem puzzling how the activation entropies can be different.

The resolution of this apparent paradox is that under the constant applied stress, the nucleation of a dislocation loop causes a strain increase, i.e.  $\sigma(n=0, T, \gamma) = \sigma(n_c, T, \gamma^+)$ , with  $\gamma^+ > \gamma$ . Based on this result, one can show that the difference in the activation entropies,  $\Delta S_c \equiv S_c(\sigma) - S_c(\gamma)$ , equals  $S(n=0, T, \gamma^+) - S(n=0, T, \gamma)$ , which is the entropy difference

of the perfect crystal at two slightly different strains. We can further show that  $\Delta S_c = -\Omega_c(\sigma)\partial\sigma/\partial T|_\gamma$ , where  $\Omega_c \equiv -\partial G_c/\partial\sigma|_T$  is the activation volume and  $-\partial\sigma/\partial T|_\gamma$  describes the thermal softening effect. Hence  $\Delta S_c$  is always positive for nucleation processes in solids driven by shear stress. In the case of homogeneous dislocation nucleation  $\Delta S_c$  as large as  $39 k_B$  is observed for homogeneous dislocation nucleation, which is mainly caused by its large activation volume  $\Omega_c$ . The numerical results enable us to examine the approximation<sup>17</sup> based on the so-called thermodynamic “compensation law”<sup>39</sup>, which states that the activation entropy is proportional to the activation enthalpy (or energy). We find that  $S_c(\gamma)$  can be roughly approximated by  $E_c(\gamma)/T^*$  with  $T^* \approx 3000$  K while  $S_c(\sigma)$  is not proportional to  $H_c(\sigma)$  (see SI appendix).

To assess the applicability of these conclusions in heterogeneous nucleation, we studied dislocation nucleation from the corner of a [001]-oriented copper nanorod with {100} side surfaces under axial compression (see Methods). Fig. 4(b) plots the activation free energy barrier as a function of axial compressive stress  $\sigma$ , which shows significant reduction of the activation free energy with temperature. For example, at the compressive elastic strain of  $\epsilon = 0.03$ , the compressive stress is  $\sigma = 1.50$  GPa at  $T = 0$  K. The activation entropy  $S_c(\epsilon)$  at this elastic strain equals  $9k_B$ , whereas the activation entropy  $S_c(\sigma)$  at this stress equals  $17k_B$ . Fig. 4(c) plots the contour lines of the predicted dislocation nucleation rate (per nucleation site) as a function of  $T$  and  $\sigma$ . To show the physical effect of the large activation entropies, the dashed lines plot the rate predictions if the effect of  $S_c(\sigma)$  were completely neglected. Significant deviations between the two sets of contour lines are observed, especially for  $T \geq 300$  K and  $\sigma \leq 1.5$  GPa. For example, at  $T = 300$  K and  $\sigma = 1.5$  GPa (where a thick and a thin contour line cross), the neglect of activation entropy would cause an underestimate of the nucleation rate by 10 orders of magnitude.

In summary, we have shown that the Becker-Döring theory combined with free energy barriers determined by umbrella sampling can accurately predict the rate of homogeneous dislocation nucleation. In both homogeneous and heterogeneous dislocation nucleation, a large activation entropy at constant elastic strain is observed, and is attributed to the weakening of atomic bonds due to thermal expansion. An even larger activation entropy is observed at constant stress, due to thermal softening. Both effects are anharmonic in nature, and emphasize the need to go beyond harmonic approximation in the application of rate theories in solids. We believe our methods and the general conclusions are applicable



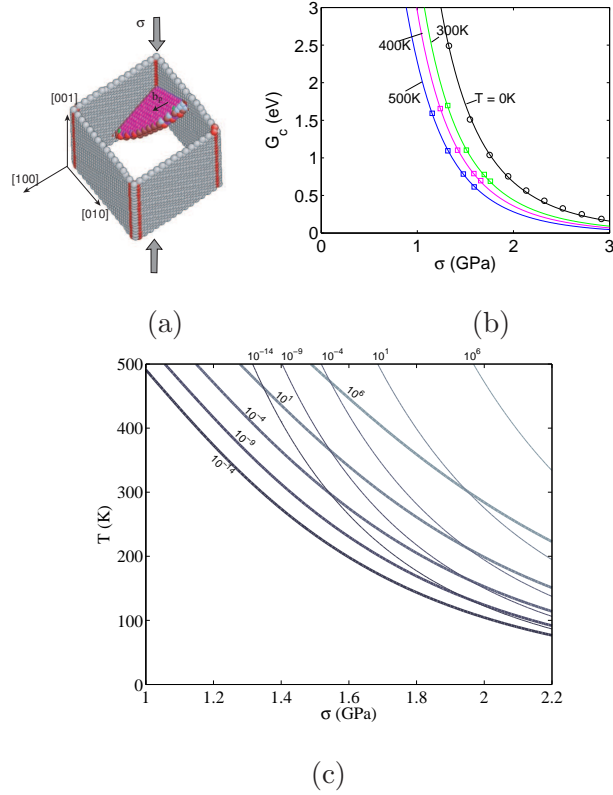


FIG. 4. (a) Heterogeneous dislocation nucleation in a copper nanorod under compression, visualized by Atomeye<sup>40</sup>. (b)  $G_c$  as a function compressive stress  $\sigma$  at different  $T$ . (c) Contour lines of dislocation nucleation rate per site  $I$  as a function of  $T$  and  $\sigma$ . The predictions with and without accounting for activation entropy  $S_c(\sigma)$  are plotted in thick and thin lines, respectively. The nucleation rate of  $I \sim 10^6 \text{s}^{-1}$  per site is accessible in typical MD time scales while nucleation rate of  $I \sim 10^{-4}-10^{-9}$  is accessible in typical experimental time scales, depending on the number of nucleation sites.

to a wide range of nucleation processes in solids that are driven by shear stress, including cross slip, twinning and martensitic phase transformation.

## Methods:

**Molecular Dynamics:** The simulation cell for homogeneous dislocation nucleation has dimension  $8[11\bar{2}] \times 6[111] \times 3[1\bar{1}0]$ . Periodic boundary conditions (PBC) are applied to all 3 directions. To reduce artifacts from periodic image interactions, the applied stress is always large enough so that the diameter of critical dislocation loop is smaller

than half the width of the simulation cell.

The shear strain  $\gamma$  is the  $x$ - $y$  component of the engineering strain. The following procedure is used to obtain pure shear stress-strain curve shown in Fig. 1(b). At each temperature  $T$  and shear strain  $\gamma_{xy}$ , a series of 2 ps MD simulations under the canonical, constant temperature-constant volume (NVT) ensemble are performed. After each simulation, all strain components except  $\gamma_{xy}$  are adjusted according to the average Virial stress until  $\sigma_{xy}$  is the only non-zero stress component. The shear strain is then increased by 0.01 and the process repeats until the crystal collapses spontaneously. The shear stress-strain data are fitted to a polynomial function,  $\sigma(\gamma, T) = \sum_{i=0}^2 \sum_{j=0}^2 a_{ij} \gamma^i T^j$ .

To obtain average nucleation time at  $\sigma_{xy} = 2.16$  GPa ( $\gamma = 0.135$ ) at 300 K, we performed 192 independent MD simulations using the NVT ensemble with random initial velocities. Each simulation runs for 4 ns. If dislocation nucleation occurs during this period, the nucleation time is recorded. This information is used to construct the function  $P_s(t)$ , which is the fraction of MD simulation cells in which dislocation nucleation has not occurred at time  $t$ .  $P_s(t)$  can be well fitted to the form of  $\exp(-I^{\text{MD}}t)$  to extract the nucleation rate  $I^{\text{MD}}$ .

To compute the attachment rate  $f_c^+$ , we collect from umbrella sampling an ensemble of 500 atomic configurations for which  $n = n_c$ , and run MD simulations using each configuration as an initial condition. The initial velocities are randomized according to Boltzmann’s distribution. The mean square change of the loop size,  $\langle \Delta n^2(t) \rangle$ , as shown in Fig. 2(b), is fitted to a straight line,  $2f_c^+t$ , in order to extract  $f_c^{+28}$ .

**Free energy barrier calculations:** The reaction coordinate  $n$  is defined for each atomic configurations in the following way. An atom is labelled as “slipped” if its distance from any of its original nearest neighbors has changed by more than the critical distance  $d_c$ <sup>29</sup>. We choose  $d_c = 0.33\text{\AA}$ ,  $0.38\text{\AA}$  and  $0.43\text{\AA}$  for  $T \leq 400$  K,  $T = 500$  K and  $T = 600$  K, respectively. The “slipped” atoms are grouped into clusters; two atoms belong to the same cluster if their distance is less than cutoff distance  $r_c$  ( $3.4\text{\AA}$ ). The reaction coordinate  $n$  is the number of atoms in the largest cluster divided by two.

To perform umbrella sampling, a bias potential  $k_B \hat{T} (n - \bar{n})^2$  is superimposed on the EAM potential, where  $\hat{T} = 40$  K and  $\bar{n}$  is the center of the sampling window. We

choose  $\hat{T}$  empirically so that the width of the sampling window on the  $n$ -axis is about 10. The activation Helmholtz free energy for homogeneous nucleation data can be fitted very well by a polynomial function,  $F_c(\gamma, T) = \sum_{i=0}^2 \sum_{j=0}^2 b_{ij} \gamma^i T^j$  in the range of  $0.09 \leq \gamma \leq 0.12$  and  $0 \leq T \leq 500\text{K}$ .

For heterogeneous dislocation nucleation, the size of the copper nanorod<sup>17</sup> is  $15[100] \times 15[010] \times 20[001]$  with PBC along  $[001]$ . The activation Gibbs free energy for heterogeneous nucleation is fitted to an empirical form  $G_c(\sigma, T) = A((\sigma/\sigma_0)^p - 1)^q - B\sigma^l T$ .

The error bar of activation free energies is about  $0.5k_B T$ . Hence, the error bar of activation entropies is about  $0.5k_B$ .

## ACKNOWLEDGMENTS

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